

Low capacitance unidirectional fivefold ESD protection diode arrays

Rev. 1 — 25 August 2010

**Product data sheet** 

### 1. Product profile

### 1.1 General description

Low capacitance unidirectional fivefold ElectroStatic Discharge (ESD) protection diode arrays in a leadless ultra small SOT891 Surface-Mounted Device (SMD) plastic package designed to protect up to five unidirectional signal lines from the damage caused by ESD and other transients.

### 1.2 Features and benefits

- ESD protection of up to five lines
- Low diode capacitance
- Max. peak pulse power: P<sub>PP</sub> = 30 W
- Low clamping voltage: V<sub>CL</sub> = 9.5 V
- AEC-Q101 qualified

- Very low leakage current: I<sub>RM</sub> = 0.5 μA
- ESD protection up to 20 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); I<sub>PP</sub> = 3.2 A

### 1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Communication systems
- Portable electronics
- Subscriber Identity Module (SIM) card protection

#### 1.4 Quick reference data

Table 1. Quick reference data  $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
$V_{RWM}$	reverse standoff voltage					
	PESD3V3L5UK		-	-	3.3	V
	PESD5V0L5UK		-	-	5.0	V
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0 V$				
	PESD3V3L5UK		-	20	24	pF
	PESD5V0L5UK		-	18.5	22	pF



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## 2. Pinning information

Table 2. Pinning

-		
Description	Simplified outline	Graphic symbol
cathode (diode 1)		
common anode		1 6
cathode (diode 2)		2 5
cathode (diode 3)		3
cathode (diode 4)		006aaa159
cathode (diode 5)	bottom view	
	cathode (diode 1) common anode cathode (diode 2) cathode (diode 3) cathode (diode 4)	cathode (diode 1)  common anode  cathode (diode 2)  cathode (diode 3)  cathode (diode 4)  cathode (diode 5)

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD3V3L5UK	-	plastic extremely thin small outline package;	SOT891
PESD5V0L5UK		no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm	

## 4. Marking

Table 4. Marking codes

Type number	Marking code
PESD3V3L5UK	P4
PESD5V0L5UK	P5

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
P <sub>PP</sub>	peak pulse power	t <sub>p</sub> = 8/20 μs	[1][2] -		
	PESD3V3L5UK		-	28	W
	PESD5V0L5UK		-	30	W
I <sub>PP</sub>	peak pulse current	$t_p = 8/20 \ \mu s$	[1][2] -		
	PESD3V3L5UK		-	3.2	Α
	PESD5V0L5UK		-	3.1	Α

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 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Non-repetitive current pulse  $8/20~\mu s$  exponential decay waveform according to IEC 61000-4-5.

Table 6. ESD maximum ratings

T<sub>amb</sub> = 25 °C unless otherwise specified.

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Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						
$V_{ESD}$	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2]			
	PESD3V3L5UK			-	15	kV
	PESD5V0L5UK			-	20	kV
	PESD3V3L5UK PESD5V0L5UK	machine model	[2]	-	400	V
	PESD3V3L5UK PESD5V0L5UK	MIL-STD-883 (human body model)		-	8	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

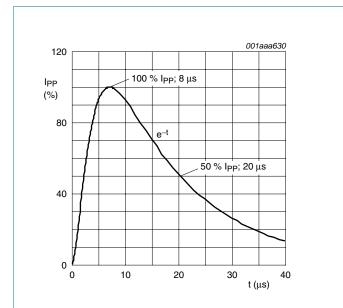
Table 7. ESD standards compliance

Standard	Conditions
Per diode	
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

<sup>[2]</sup> Measured from pin 1, 3, 4, 5 or 6 to pin 2.

<sup>[2]</sup> Measured from pin 1, 3, 4, 5 or 6 to pin 2.

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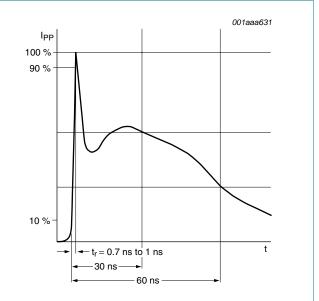


Fig 2. ESD pulse waveform according to IEC 61000-4-2

## 6. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diod	е						
$V_{RWM}$	reverse standoff voltage						
	PESD3V3L5UK			-	-	3.3	V
	PESD5V0L5UK			-	-	5.0	V
I <sub>RM</sub>	reverse leakage current						
	PESD3V3L5UK	$V_{RWM} = 3.3 V$		-	0.4	2	μΑ
	PESD5V0L5UK	$V_{RWM} = 5.0 V$		-	0.08	0.5	μΑ
$V_{BR}$	breakdown voltage	$I_R = 1 \text{ mA}$					
	PESD3V3L5UK			5.3	5.6	5.9	V
	PESD5V0L5UK			6.47	6.8	7.14	V
C <sub>d</sub>	diode capacitance	f = 1 MHz; $V_R = 0 V$					
	PESD3V3L5UK			-	20	24	pF
	PESD5V0L5UK			-	18.5	22	pF
$V_{CL}$	clamping voltage		[1][2]				
	PESD3V3L5UK	I <sub>PP</sub> = 3.1 A		-	-	9.5	V
	PESD5V0L5UK	I <sub>PP</sub> = 3 A		-	-	9.9	V
r <sub>dif</sub>	differential resistance	$I_R = 5 \text{ mA}$					
	PESD3V3L5UK			-	5	16	Ω
	PESD5V0L5UK			-	2.5	8	Ω

<sup>[1]</sup> Non-repetitive current pulse  $8/20~\mu s$  exponential decay waveform according to IEC 61000-4-5.

<sup>[2]</sup> Measured from pin 1, 3, 4, 5 or 6 to pin 2.

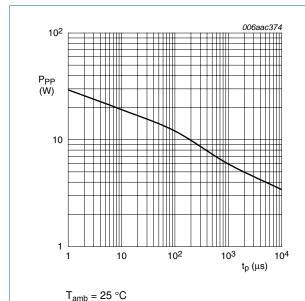


Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

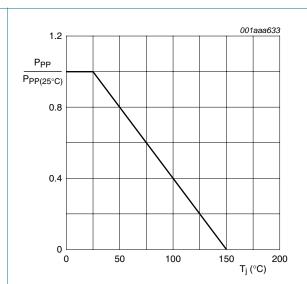
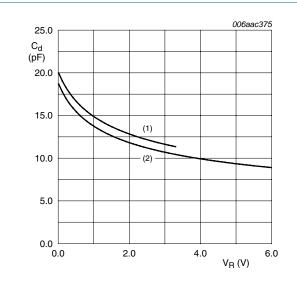


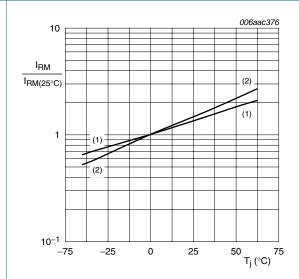
Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



f = 1 MHz; T<sub>amb</sub> = 25 °C

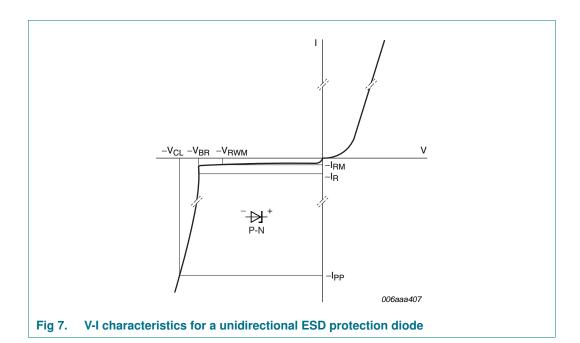
- (1) PESD3V3L5UK
- (2) PESD5V0L5UK

Fig 5. Diode capacitance as a function of reverse voltage; typical values

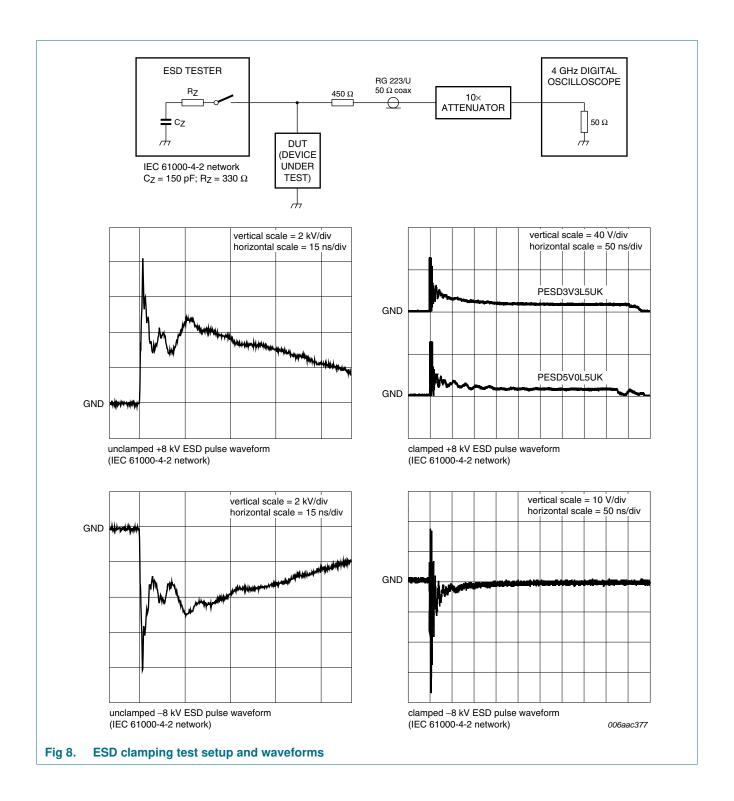


- (1) PESD3V3L5UK
- (2) PESD5V0L5UK

Fig 6. Relative variation of reverse current as a function of junction temperature; typical values

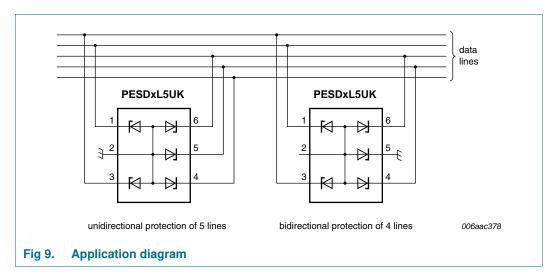


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## 7. Application information

The PESD3V3L5UK and the PESD5V0L5UK are designed for the protection of up to five unidirectional data or signal lines from the damage caused by ESD and surge pulses. The devices may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESD3V3L5UK provides a surge capability of 28 W per line and the PESD5V0L5UK provides a surge capability of 30 W per line for an 8/20  $\mu s$  waveform.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

#### 8. Test information

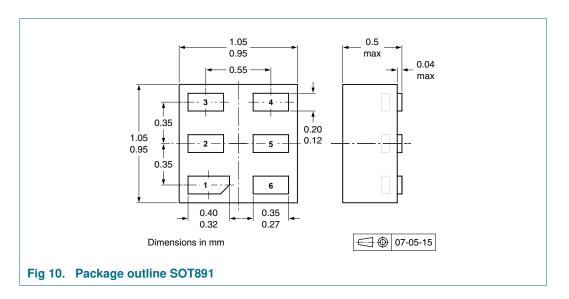
### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

PESD3V3L5UK\_PESD5V0L5UK

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## 9. Package outline



## 10. Packing information

Table 9. Packing methods

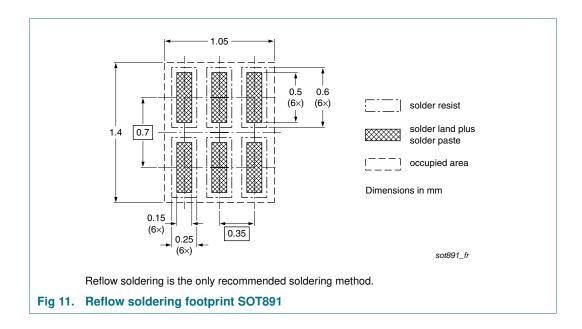
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing quantity
				5000
PESD3V3L5UK	SOT891	4 mm pitch, 8 mm tape and reel; T4	[2]	-132
PESD5V0L5UK				

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

<sup>[2]</sup> T4: 90° rotated reverse taping

## 11. Soldering



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## 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD3V3L5UK_ PESD5V0L5UK v.1	20100825	Product data sheet	-	-

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### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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### **NXP Semiconductors**

# PESD3V3L5UK; PESD3V3L5UK

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